



M54HC164

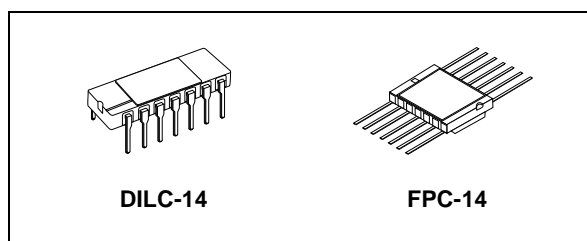
RAD-HARD 8 BIT SIPO SHIFT REGISTER

- HIGH SPEED:
 $f_{\text{MAX}} = 62\text{MHz}$ (TYP.) at $V_{\text{CC}} = 6\text{V}$
- LOW POWER DISSIPATION:
 $I_{\text{CC}} = 4\mu\text{A}$ (MAX.) at $T_{\text{A}} = 25^{\circ}\text{C}$
- HIGH NOISE IMMUNITY:
 $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$ (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{\text{OH}}| = I_{\text{OL}} = 4\text{mA}$ (MIN)
- BALANCED PROPAGATION DELAYS:
 $t_{\text{PLH}} \approx t_{\text{PHL}}$
- WIDE OPERATING VOLTAGE RANGE:
 V_{CC} (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE WITH 54 SERIES 164
- SPACE GRADE-1: ESA SCC QUALIFIED
- 50 krad QUALIFIED, 100 krad AVAILABLE ON REQUEST
- NO SEL UNDER HIGH LET HEAVY IONS IRRADIATION
- DEVICE FULLY COMPLIANT WITH SCC-9306-041

DESCRIPTION

The M54HC164 is an high speed CMOS 8 BIT SIPO SHIFT REGISTER fabricated with silicon gate C²MOS technology.

The M54HC164 is an 8 bit shift register with serial data entry and an output from each of the eight

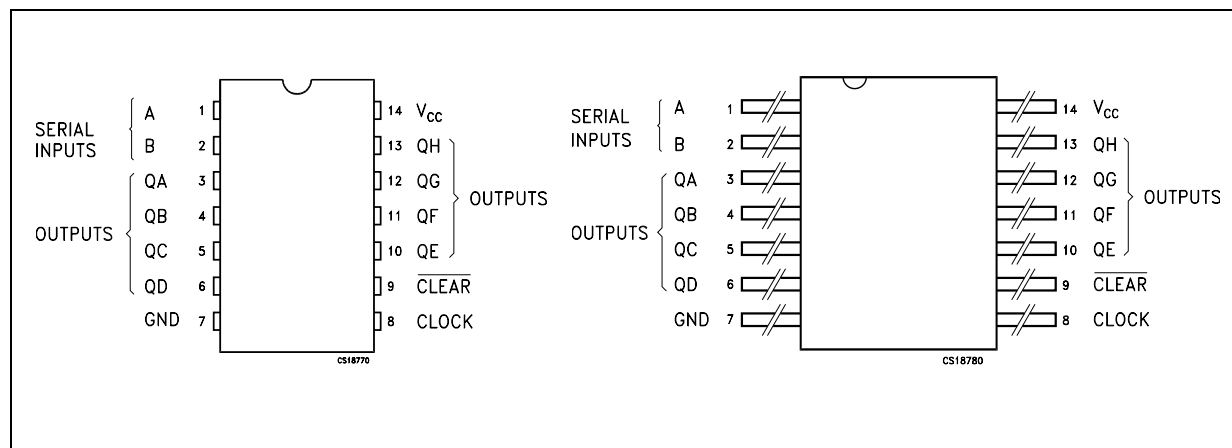


ORDER CODES

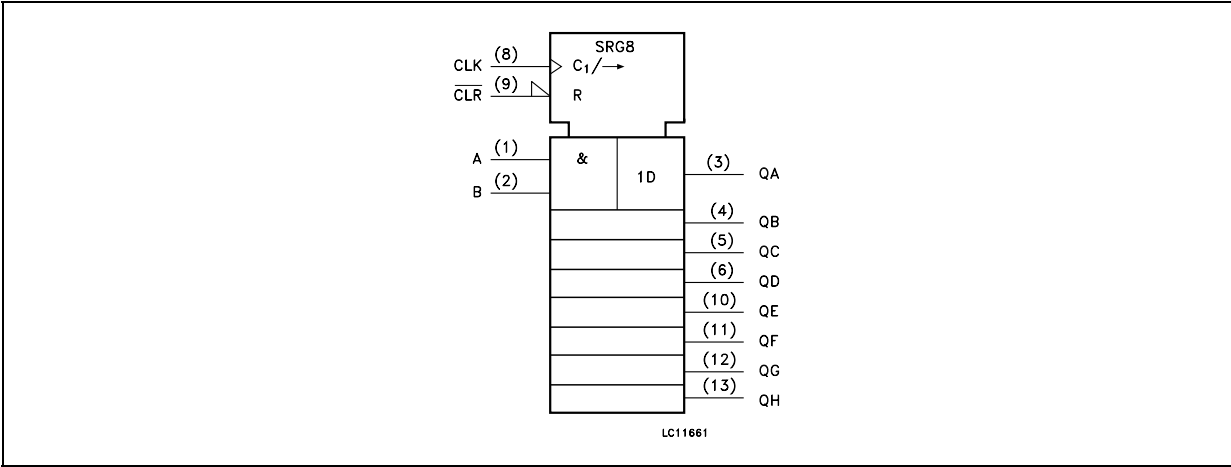
| PACKAGE | FM | EM |
|---------|-----------|------------|
| DILC | M54HC164D | M54HC164D1 |
| FPC | M54HC164K | M54HC164K1 |

stages. Data is entered serially through one of two inputs (A or B), either of these inputs can be used as an active high enable for data entry through the other input. An unused input must be high, or both inputs connected together. Each low-to-high transition on the clock inputs shifts data one place to the right and enters into QA the logic NAND of the two data inputs (A x B), the data that existed before the rising clock edge. A low level on the clear input overrides all other inputs and clears the register asynchronously, forcing all Q outputs low. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

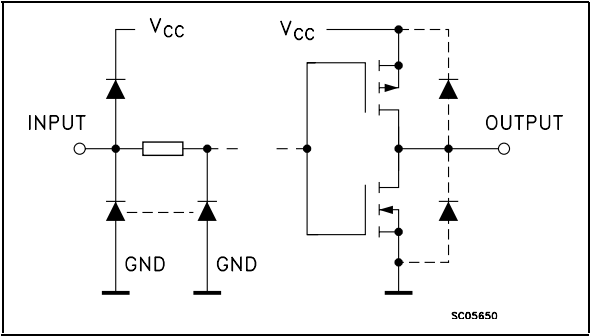
PIN CONNECTION



IEC LOGIC SYMBOLS



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

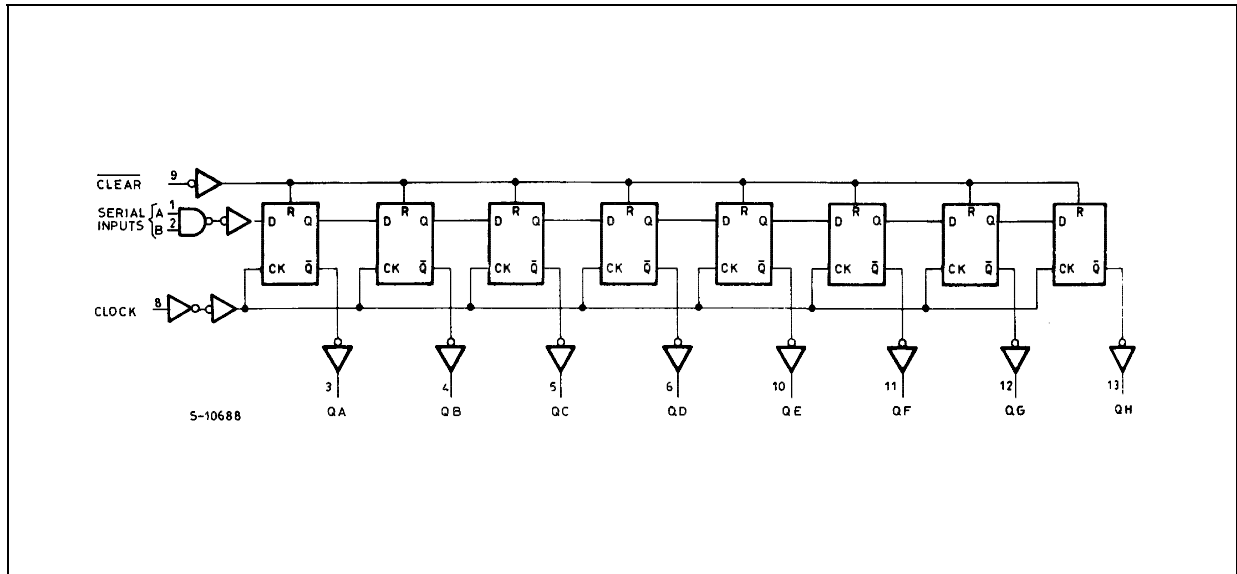
| PIN N° | SYMBOL | NAME AND FUNCTION |
|----------------------------|-----------------|---|
| 1, 2 | A, B | Data Inputs |
| 3, 4, 5, 6, 10, 11, 12, 13 | QA to QH | Outputs |
| 8 | CLOCK | Clock Input (LOW to HIGH, Edge Triggered) |
| 9 | CLEAR | Master Reset Input |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive Supply Voltage |

TRUTH TABLE

| INPUTS | | | | OUTPUTS | | | |
|--------|-------|-----------|---|-----------|-----|-------|-----|
| CLEAR | CLOCK | SERIAL IN | | QA | QB | | QH |
| | | A | B | | | | |
| L | X | X | X | L | L | | L |
| H | | X | X | NO CHANGE | | | |
| H | | L | X | L | QAn | | QGn |
| H | | X | L | L | QAn | | QGn |
| H | | H | H | H | QAn | | QGn |

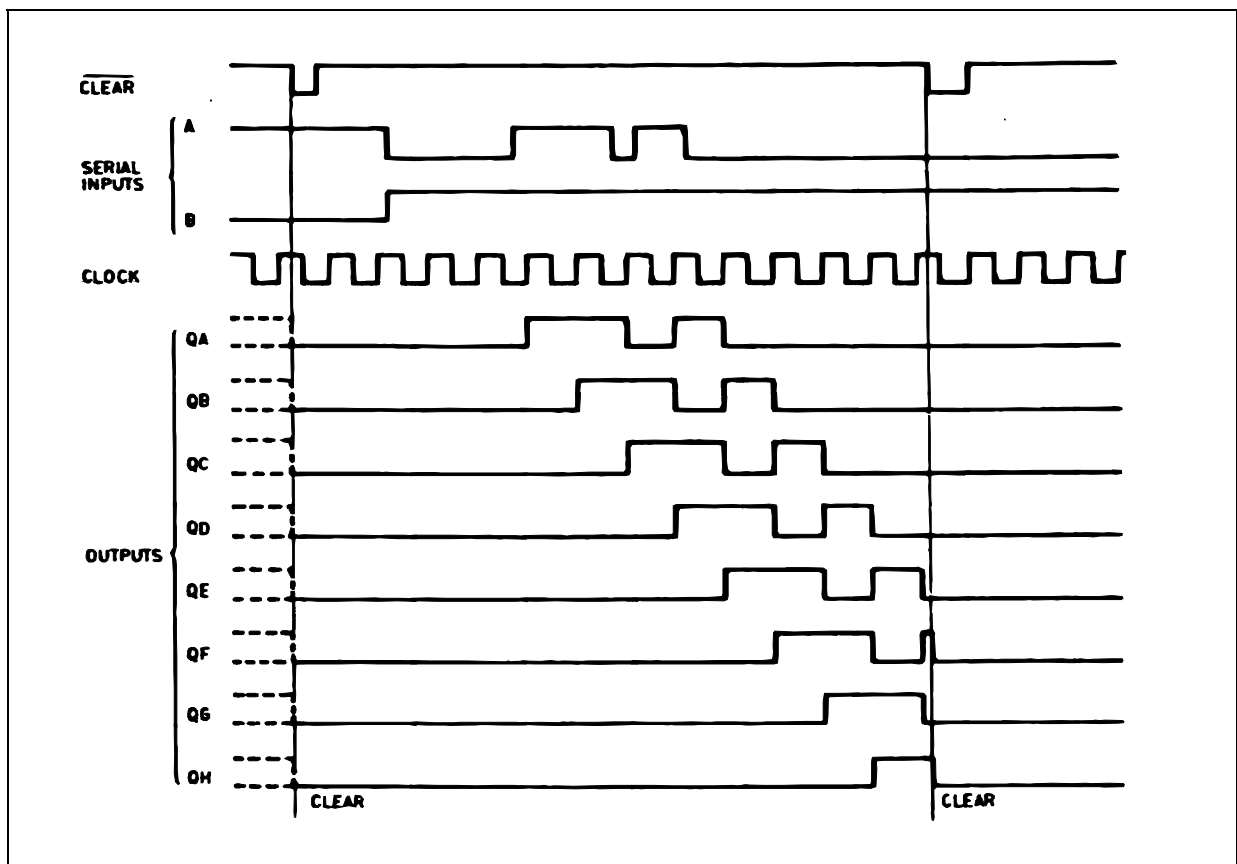
X : Don't Care
QAn - QGn : The level of QA - QG, respectively, before the most-recent transition of the clock

LOGIC DIAGRAM



This logic diagram has not be used to estimate propagation delays

TIMING CHART



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-----------------------|-------------------------------|------------------------|------|
| V_{CC} | Supply Voltage | -0.5 to +7 | V |
| V_I | DC Input Voltage | -0.5 to $V_{CC} + 0.5$ | V |
| V_O | DC Output Voltage | -0.5 to $V_{CC} + 0.5$ | V |
| I_{IK} | DC Input Diode Current | ± 20 | mA |
| I_{OK} | DC Output Diode Current | ± 20 | mA |
| I_O | DC Output Current | ± 25 | mA |
| I_{CC} or I_{GND} | DC V_{CC} or Ground Current | ± 50 | mA |
| P_D | Power Dissipation | 300 | mW |
| T_{stg} | Storage Temperature | -65 to +150 | °C |
| T_L | Lead Temperature (10 sec) | 265 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Value | Unit |
|---------------------------------|--------------------------|------------------------|----------------------|------|
| V _{CC} | Supply Voltage | | 2 to 6 | V |
| V _I | Input Voltage | | 0 to V _{CC} | V |
| V _O | Output Voltage | | 0 to V _{CC} | V |
| T _{op} | Operating Temperature | | -55 to 125 | °C |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 2.0V | 0 to 1000 | ns |
| | | V _{CC} = 4.5V | 0 to 500 | ns |
| | | V _{CC} = 6.0V | 0 to 400 | ns |

DC SPECIFICATIONS

| Symbol | Parameter | Test Condition | | Value | | | | | | | Unit | |
|-----------------|---------------------------|------------------------|---|-----------------------|------|-------|-------------|------|--------------|------|------|--|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | | |
| V _{IH} | High Level Input Voltage | 2.0 | | 1.5 | | | 1.5 | | 1.5 | | V | |
| | | 4.5 | | 3.15 | | | 3.15 | | 3.15 | | | |
| | | 6.0 | | 4.2 | | | 4.2 | | 4.2 | | | |
| V _{IL} | Low Level Input Voltage | 2.0 | | | | 0.5 | | 0.5 | | 0.5 | V | |
| | | 4.5 | | | | 1.35 | | 1.35 | | 1.35 | | |
| | | 6.0 | | | | 1.8 | | 1.8 | | 1.8 | | |
| V _{OH} | High Level Output Voltage | 2.0 | I _O =-20 μA | 1.9 | 2.0 | | 1.9 | | 1.9 | | V | |
| | | 4.5 | I _O =-20 μA | 4.4 | 4.5 | | 4.4 | | 4.4 | | | |
| | | 6.0 | I _O =-20 μA | 5.9 | 6.0 | | 5.9 | | 5.9 | | | |
| | | 4.5 | I _O =-4.0 mA | 4.18 | 4.31 | | 4.13 | | 4.10 | | | |
| | | 6.0 | I _O =-5.2 mA | 5.68 | 5.8 | | 5.63 | | 5.60 | | | |
| V _{OL} | Low Level Output Voltage | 2.0 | I _O =20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V | |
| | | 4.5 | I _O =20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | | |
| | | 6.0 | I _O =20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | | |
| | | 4.5 | I _O =4.0 mA | | 0.17 | 0.26 | | 0.33 | | 0.40 | | |
| | | 6.0 | I _O =5.2 mA | | 0.18 | 0.26 | | 0.33 | | 0.40 | | |
| I _I | Input Leakage Current | 6.0 | V _I = V _{CC} or GND | | | ± 0.1 | | ± 1 | | ± 1 | μA | |
| I _{CC} | Quiescent Supply Current | 6.0 | V _I = V _{CC} or GND | | | 4 | | 40 | | 80 | μA | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

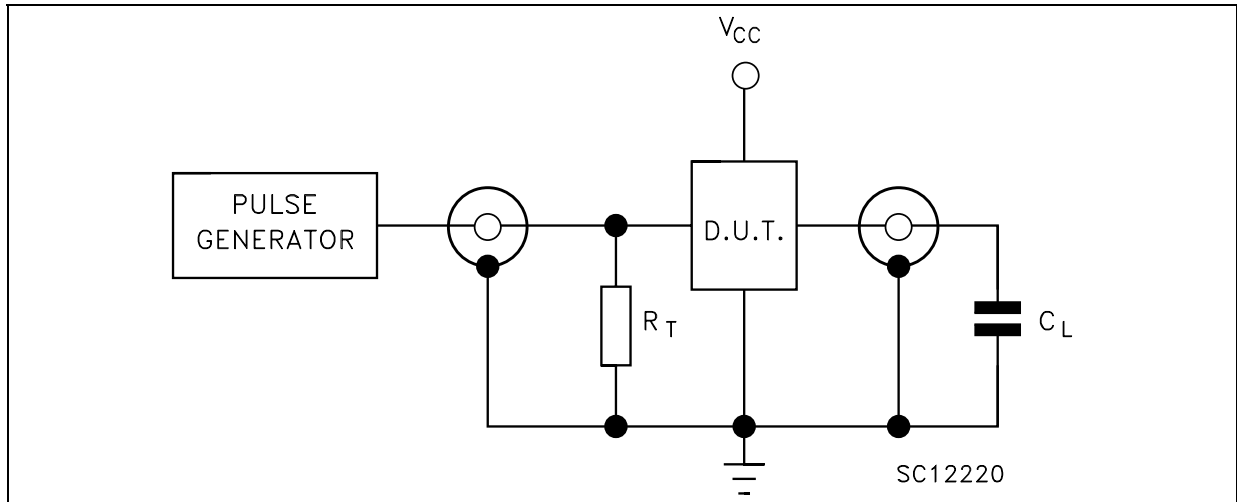
| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|--|------------------------------------|------------------------|--|-----------------------|------|------|-------------|------|--------------|------|------|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| t _{TLH} t _{THL} | Output Transition Time | 2.0 | | | 30 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (CLOCK - Q) | 2.0 | | | 57 | 160 | | 200 | | 240 | ns |
| | | 4.5 | | | 19 | 32 | | 40 | | 48 | |
| | | 6.0 | | | 16 | 27 | | 34 | | 41 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (CLEAR - Q) | 2.0 | | | 60 | 175 | | 220 | | 265 | ns |
| | | 4.5 | | | 20 | 35 | | 44 | | 53 | |
| | | 6.0 | | | 17 | 30 | | 37 | | 45 | |
| f _{MAX} | Maximum Clock Frequency | 2.0 | | 6.2 | 18 | | 5.0 | | 4.2 | | MHz |
| | | 4.5 | | 31 | 53 | | 25 | | 21 | | |
| | | 6.0 | | 37 | 62 | | 30 | | 25 | | |
| t _{W(H)} t _{W(L)} | Minimum Pulse Width (CLOCK) | 2.0 | | | 24 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 6 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 5 | 13 | | 16 | | 19 | |
| t _{W(L)} | Minimum Pulse Width (CLEAR) | 2.0 | | | 40 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 10 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 9 | 13 | | 16 | | 19 | |
| t _s | Set-up Time (A, B - CK) | 2.0 | | 50 | | | 65 | | 75 | | ns |
| | | 4.5 | | 10 | | | 13 | | 15 | | |
| | | 6.0 | | 9 | | | 11 | | 13 | | |
| t _h | Hold Time (A, B - CK) | 2.0 | | 5 | | | 5 | | 5 | | ns |
| | | 4.5 | | 5 | | | 5 | | 5 | | |
| | | 6.0 | | 5 | | | 5 | | 5 | | |
| t _{REM} | Minimum Removal Time | 2.0 | | | | 5 | | 5 | | 5 | ns |
| | | 4.5 | | | | 5 | | 5 | | 5 | |
| | | 6.0 | | | | 5 | | 5 | | 5 | |

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | | Value | | | | | | | Unit |
|-----------------|--|------------------------|--|-----------------------|------|------|-------------|------|--------------|------|------|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | |
| C _{IN} | Input Capacitance | 5.0 | | | 5 | 10 | | 10 | | 10 | pF |
| C _{PD} | Power Dissipation Capacitance (note 1) | 5.0 | | | 99 | | | | | | pF |

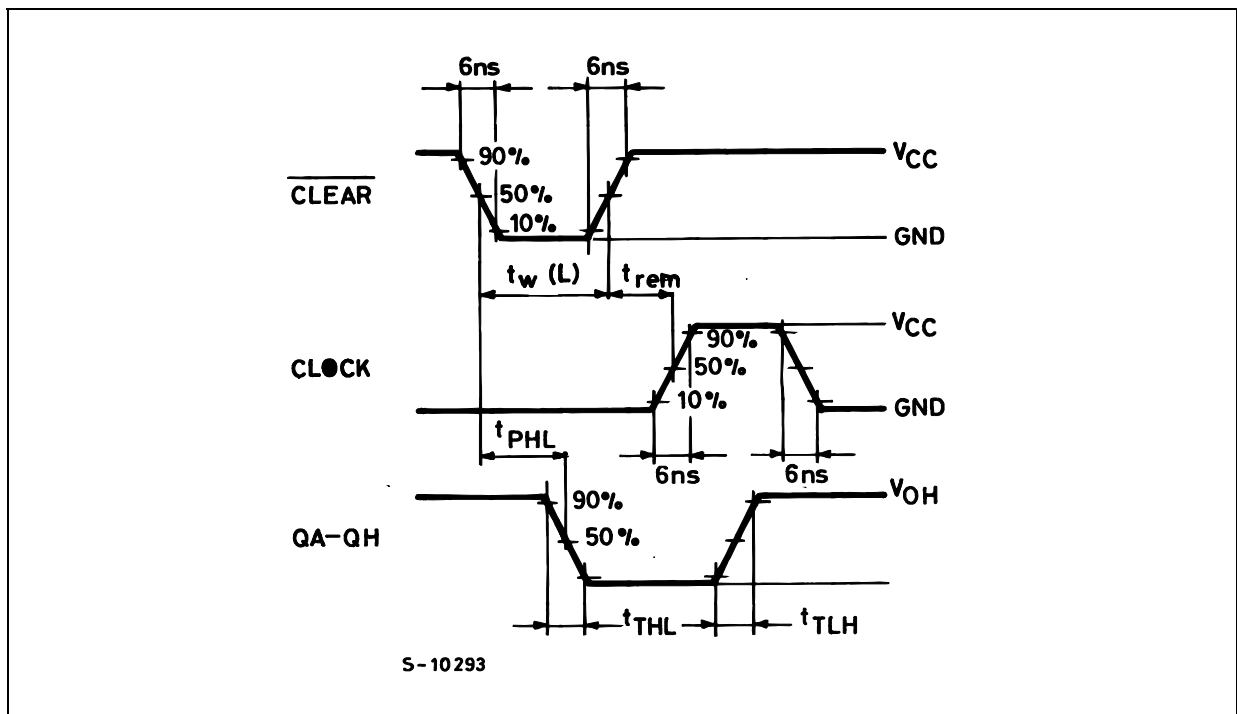
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

TEST CIRCUIT

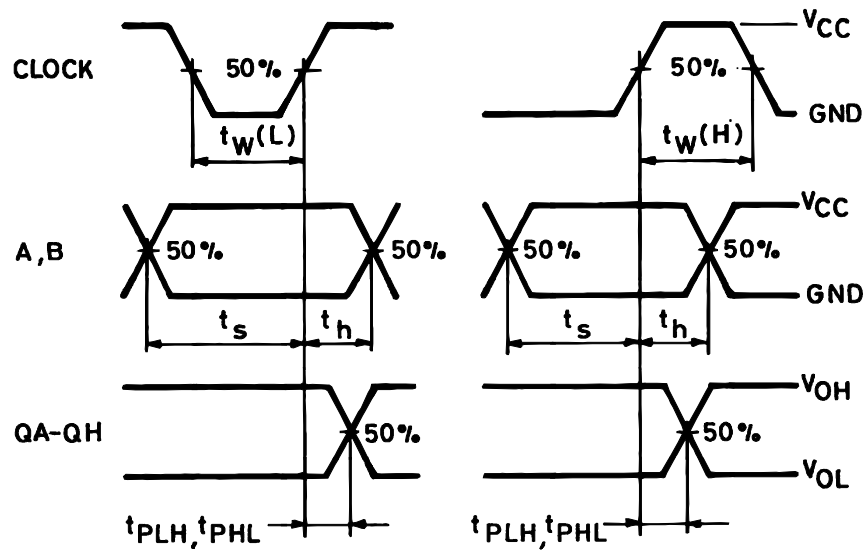


$C_L = 50\text{pF}$ or equivalent (includes jig and probe capacitance)
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

WAVEFORM 1: MINIMUM PULSE WIDTH ($\overline{\text{CLEAR}}$), MINIMUM REMOVAL TIME ($\overline{\text{CLEAR}}$ TO CLOCK)
 ($f=1\text{MHz}$; 50% duty cycle)



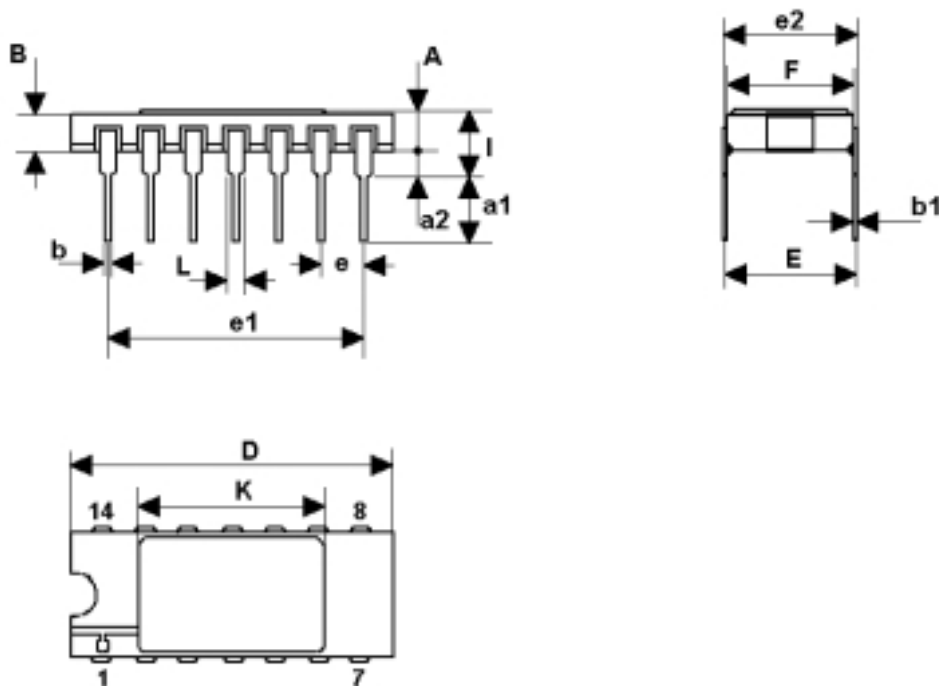
WAVEFORM 2: PROPAGATION DELAY TIMES, MINIMUM PULSE WIDTH (CLOCK), SETUP AND HOLD TIME (A, B TO CLOCK) ($f=1\text{MHz}$; 50% duty cycle)



S-10294

DILC-14 MECHANICAL DATA

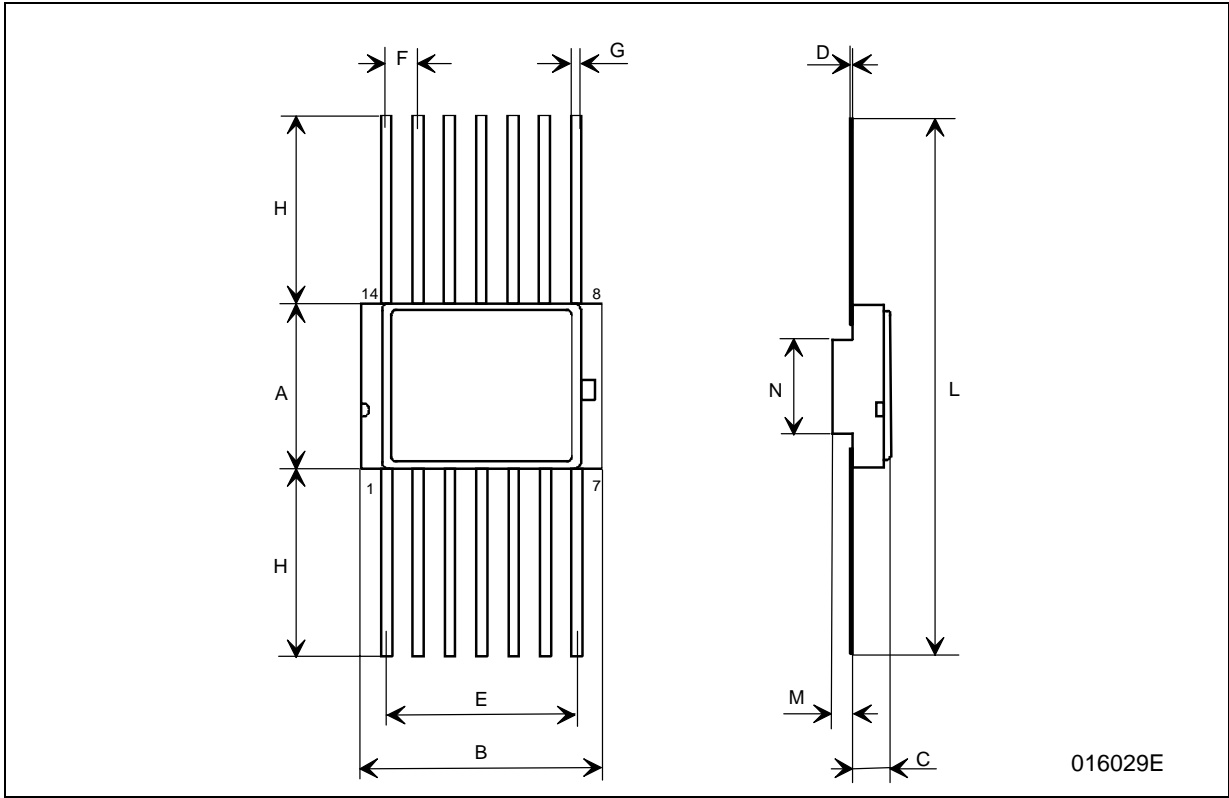
| DIM. | mm. | | | inch | | |
|------|-------|-------|-------|-------|-------|-------|
| | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A | 2.1 | | 22.54 | 0.083 | | 0.100 |
| a1 | 3.00 | | 3.70 | 0.118 | | 0.146 |
| a2 | 0.63 | 0.88 | 1.14 | 0.025 | 0.035 | 0.045 |
| B | 1.82 | 2.03 | 2.39 | 0.072 | 0.080 | 0.094 |
| b | 0.40 | 0.45 | 0.50 | 0.016 | 0.018 | 0.020 |
| b1 | 0.20 | 0.254 | 0.30 | 0.008 | 0.010 | 0.012 |
| D | 18.79 | 19.00 | 19.20 | 0.740 | 0.748 | 0.756 |
| e | 7.36 | 7.62 | 7.87 | 0.290 | 0.300 | 0.310 |
| e1 | | 2.54 | | | 0.100 | |
| e2 | 15.11 | 15.24 | 15.37 | 0.595 | 0.600 | 0.605 |
| e3 | 7.62 | 7.87 | 8.12 | 0.300 | 0.310 | 0.320 |
| F | 7.11 | | 7.75 | 0.280 | | 0.305 |
| I | | | 3.70 | | | 0.146 |
| K | 10.90 | | 12.1 | 0.429 | | 0.476 |
| L | 1.14 | 1.27 | 1.5 | 0.045 | 0.050 | 0.059 |



0016173H

FPC-14 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|-------|-------|-------|-------|-------|-------|
| | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A | 6.75 | 6.91 | 7.06 | 0.266 | 0.272 | 0.278 |
| B | 9.76 | 9.95 | 10.14 | 0.384 | 0.392 | 0.399 |
| C | 1.49 | | 1.95 | 0.059 | | 0.077 |
| D | 0.10 | 0.127 | 0.15 | 0.004 | 0.005 | 0.006 |
| E | 7.50 | 7.62 | 7.75 | 0.295 | 0.300 | 0.305 |
| F | | 1.27 | | | 0.050 | |
| G | 0.38 | 0.43 | 0.48 | 0.015 | 0.017 | 0.019 |
| H | | 6.0 | | | 0.236 | |
| L | 18.75 | | 22.0 | 0.738 | | 0.866 |
| M | | 0.38 | | | 0.015 | |
| N | | 4.31 | | | 0.170 | |



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